Supporting Information

Improved interfacial contact for pyramidal texturing of silicon heterojunction solar cells

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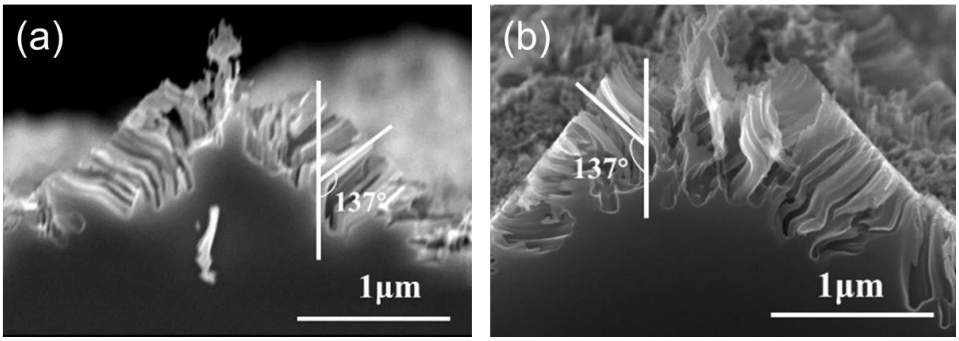

Figure S1. SEM of different $AgNO_3$ concentrations: (a) 8mM, (b) 9mM

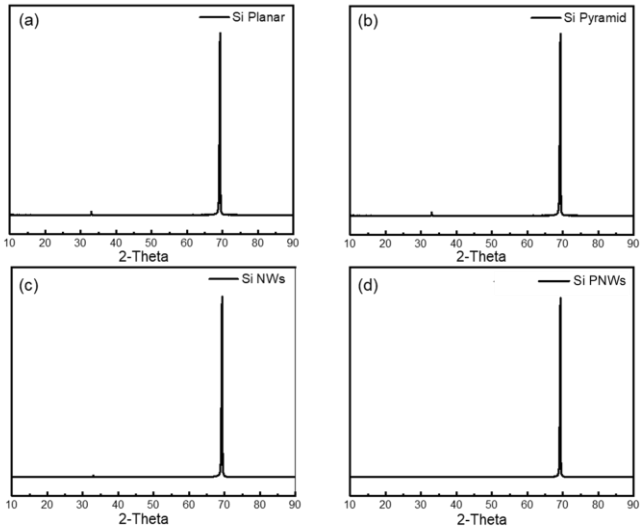

Figure S2. The XRD of different structure of samples: (a) planar Si, (b) Si pyramid, (c) SiNWs, (d) SiNWs/pyramid.

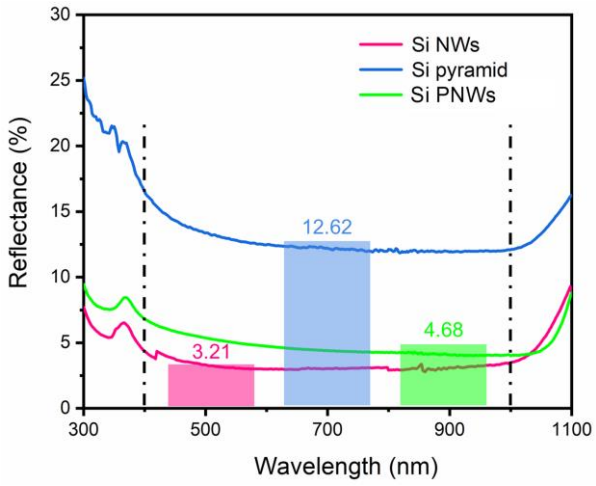

Figure S3. reflectance spectra of different silicon textures.